

Vishay Siliconix

# **Dual N-Channel 60-V (D-S) MOSFET**

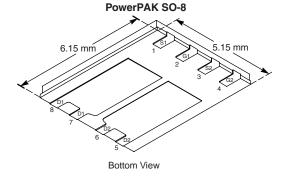
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
60	0.075 at V <sub>GS</sub> = 10 V	4.6		
	0.100 at V <sub>GS</sub> = 4.5 V	4.0		

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET<sup>®</sup> Power MOSFET
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package
- · Dual MOSFET for Space Savings

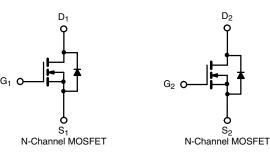


FREE



 $\textbf{Ordering Information:} \quad \text{Si7948DP-T1-E3 (Lead (Pb)-free)}$ 

Si7948DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	10 s	Steady State	Unit			
Drain-Source Voltage		$V_{DS}$	60		V		
Gate-Source Voltage		$V_{GS}$	± 20		V		
Continuous Drain Current (T <sub>.I</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	4.6	3.0			
Continuous Drain Current (1, = 150 C)	T <sub>A</sub> = 70 °C		3.6	2.4			
Pulsed Drain Current		I <sub>DM</sub>	15		Α		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.7	1.2			
Single Avalanche Current	L = 1.0 mH	I <sub>AS</sub>	15				
Single Avalanche Energy		E <sub>AS</sub>	11		mJ		
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.3	1.4	W		
Maximum Fower Dissipation	T <sub>A</sub> = 70 °C		2.1	0.9	VV		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C		
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260				

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manines are lumpition to Ameliand	t ≤ 10 s	R <sub>thJA</sub>	29	38	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		60	85	
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	4.0	5.2	

#### Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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# **Si7948DP**

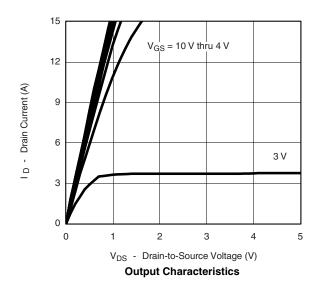
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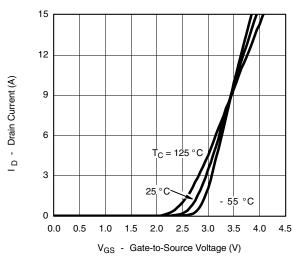


<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		3	٧		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zava Cata Valtaga Dvain Current	I <sub>DSS</sub> V <sub>DS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V			1			
Zero Gate Voltage Drain Current		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	15			Α		
	В	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4.6 A		0.060	0.075	0		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 4.0 A		0.080	0.100	Ω		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 4.6 A		6		S		
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 2.7 A, V <sub>GS</sub> = 0 V		0.8	1.2	٧		
Dynamic <sup>b</sup>								
Total Gate Charge	$Q_g$			12	20			
Gate-Source Charge	$Q_{gs}$ $V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$ $Q_{gd}$		2		nC			
Gate-Drain Charge				3.5				
Gate Resistance	$R_{g}$			1.5		Ω		
Turn-On Delay Time	t <sub>d(on)</sub>			7	20			
Rise Time	t <sub>r</sub>			8	25	ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ 15 A, $V_{GEN}$ = 10 V, $R_g$ = 2.5 $\Omega$		15	40			
Fall Time	t <sub>f</sub>			7	20			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 2.7 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$		30	60			

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



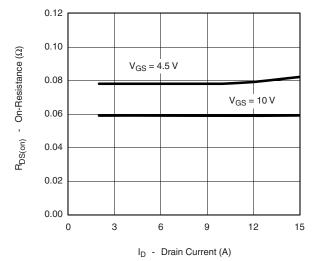


Notes: a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

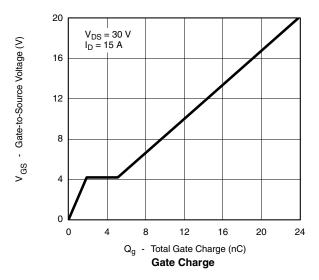


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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current



T<sub>J</sub> = 150 °C

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T<sub>J</sub> = 25 °C

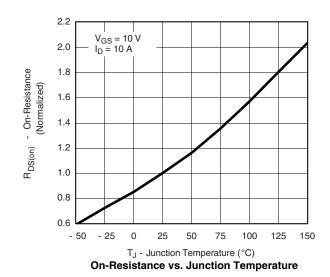
T<sub>J</sub> = 25 °C

V<sub>SD</sub> - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

800 700 C - Capacitance (pF) 600  $C_{\text{iss}}$ 500 400 300  $C_{oss}$ 200  $\mathsf{C}_{\mathsf{rss}}$ 100 0 0 12 20

V<sub>DS</sub> - Drain-to-Source Voltage (V) **Capacitance** 



0.200 0.175  $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$  - On-Resistance  $(\Omega)$ 0.150 0.125  $I_D = 4.6 A$ 0.100 0.075 0.050 0.025 0.000 2 6 0 10 V<sub>GS</sub> - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

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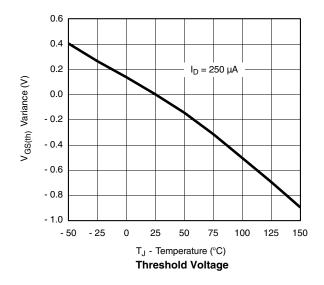
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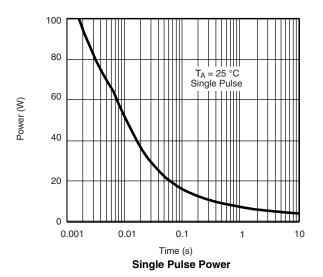
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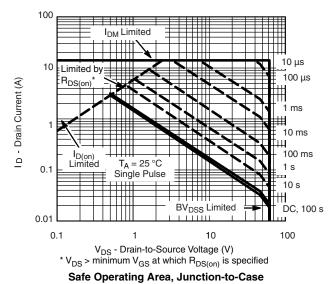
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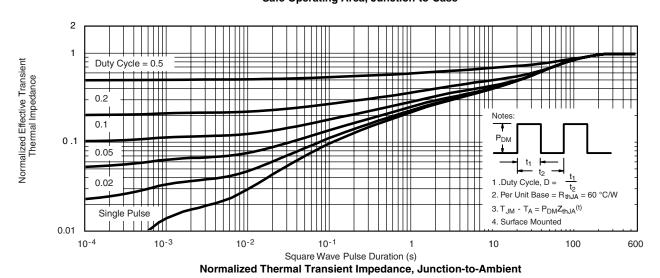
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# TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





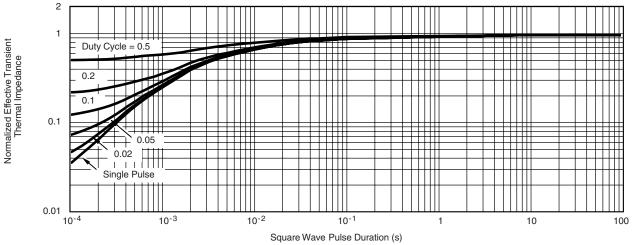






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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?72403">www.vishay.com/ppg?72403</a>.

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